HAMAMATSU

PRELIMINARY DATA

HIGH POWER QUASI-CW LASER DIODE L8411

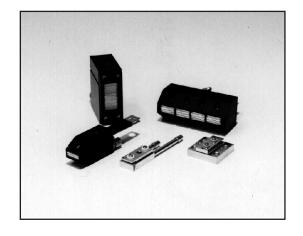
High power Quasi-CW operation

FEATURES

- High optical power : 50 to 100W/bar in average
- High stability
- Long life
- High cost performance

APPLICATIONS

- Pumping source for solid state lasers
- Materials processing
- Welding
- Soldering
- Medical systems



Our high power Quasi-CW laser diode, L8411, features several advantages such as high stability with long life, high cost performance with compact structure, and higher peak intensity. It can be applied as light source to pump solid state lasers, for material processing like welding or soldering, and for medical systems. The lasing areas consist of small laser emitters arranged in line and are thus called "Bar" structure. A high Quasi-CW output power as high as 10kW at peak was achieved by stacking ten Bars. Cooling methods can be selected from Peltier-cooling, water-cooling and Funryu-cooling (patent pending : Japan 8-139479, WO 00/11717). A high power laser module with a focusing lens and a driving electronics are optionally available.

ABSOLUTE MAXIMUM RATINGS (Each bar)

Parameter	Symbol	Low Duty Ratio Type	High Duty Ratio Type	Unit
Radiant Output Power / bar	фе	105 55		W
Reverse Voltage	VR	2.0 2.0		V
Pulse Duration	Tw	200	200	μsec
Duty Ratio	DR	1	20	%
Operating Temperature	Тор	+15 te	°C	
Storage Temperature	Tstg	-20 to	°C	

CHARACTERISTICS (Each bar, Ta=20°C)

Parameter	Symbol	Low Duty Ratio Type		High Duty Ratio Type		Linit
		Conditions	Value	Conditions	Value	Unit
Radiant Output Power / bar	фе		100		50	W
Forward Current	lF	фе=100W	120	$\phi = 50W$	80	А
Peak Emission Wavelength	λρ	фе=100W	808	фе=50W	808	nm
Spectral Radiation Half Bandwidth	$\Delta\lambda$	$\phi = 100W$	4	$\phi = 50W$	5	nm
Forward Voltage	VF	$\phi = 100W$	2.0	$\phi = 50W$	1.9	V
Beam Spread Angle : Parallel	θ//	FWHM	10	FWHM	10	° (degree)
: Vertical	$\theta \bot$		35		35	° (degree)
Lasing Threshold Current	lth		25		20	А
Array Length	-		10		10	mm
Maximum Number of Stacks	-		25		6	stack

*Contact sales stuff for emitting wave-length and radiant output power ($igoplus_{e}$) other than above.

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Figure 1: Radiant Output Power vs. Forward Current Low Duty Ratio Type (Typ.)

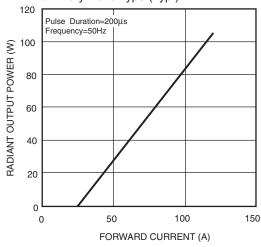
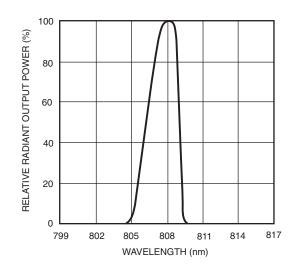
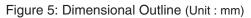
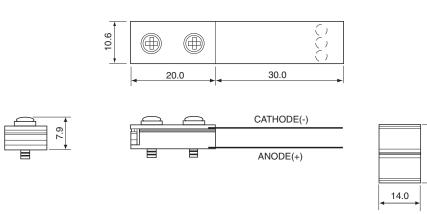


Figure 3: Typical Emission Spectrum





Low Duty Ratio Type (Peltier-cooling)



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Figure 2: Radiant Output Power vs. Forward Current High Duty Ratio Type (Typ.)

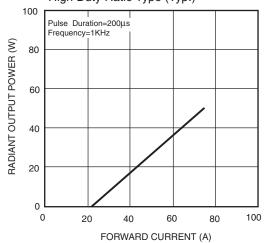
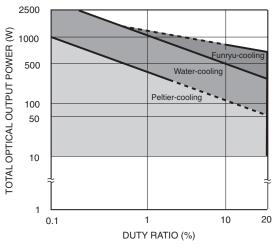
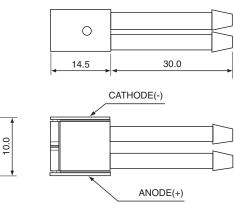


Figure 4: Relationship Between Total Optical Output Power and Duty Ratio



High Duty Ratio Type (Water-cooling)



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